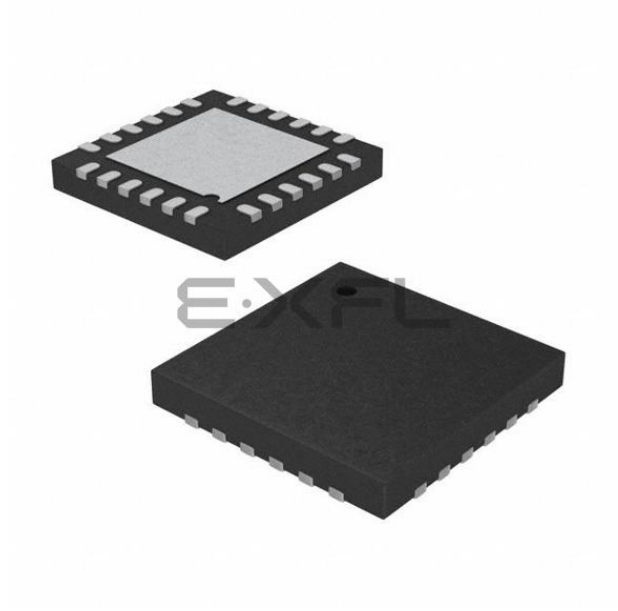

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What is "Embedded - Microcontrollers"?

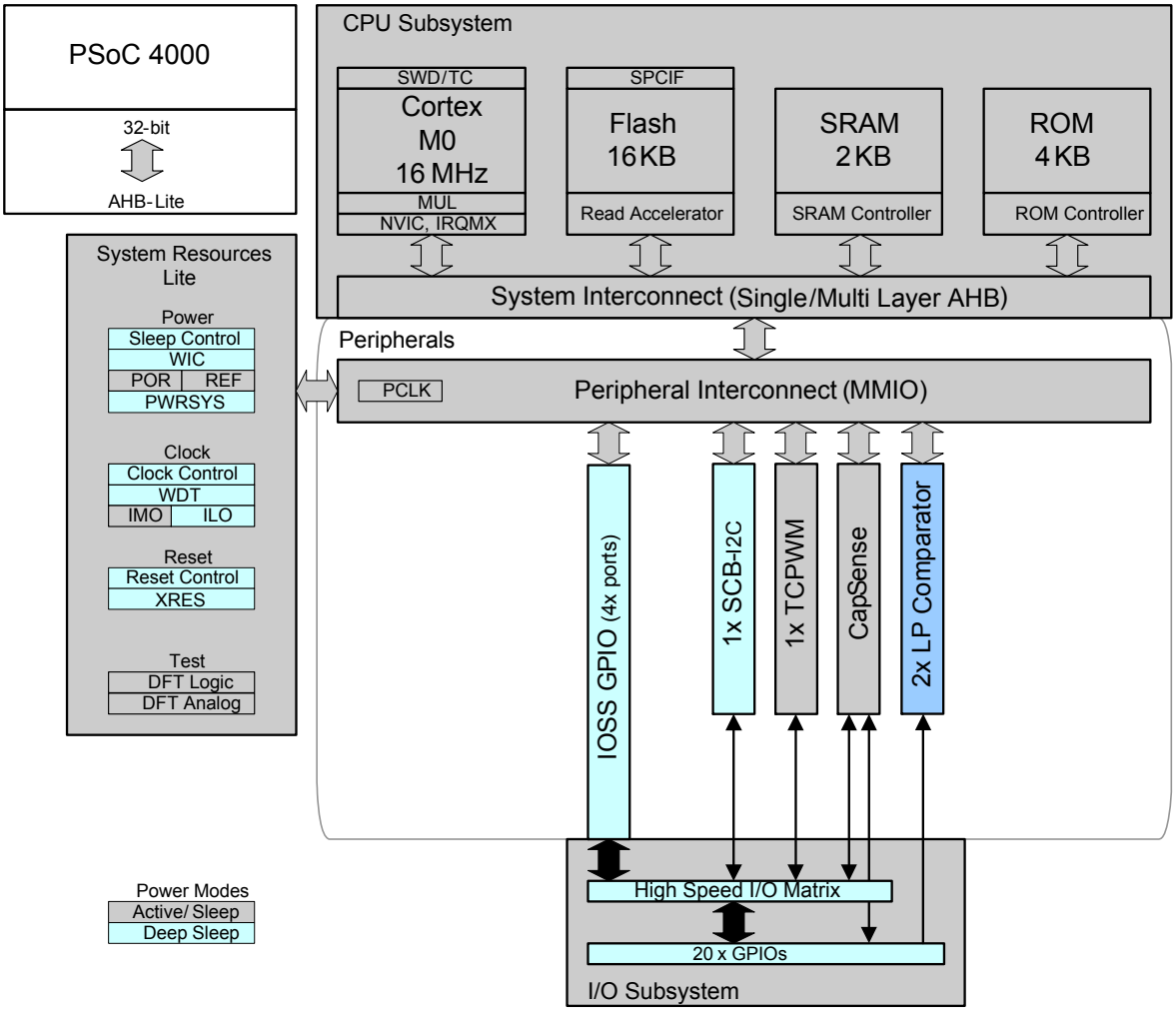
"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "Embedded - Microcontrollers"

Details	
Product Status	Obsolete
Core Processor	ARM® Cortex®-M0
Core Size	32-Bit Single-Core
Speed	16MHz
Connectivity	I²C
Peripherals	Brown-out Detect/Reset, POR, PWM, WDT
Number of I/O	20
Program Memory Size	16KB (16K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	2K x 8
Voltage - Supply (Vcc/Vdd)	1.71V ~ 5.5V
Data Converters	D/A 1x7b, 1x8b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 105°C (TA)
Mounting Type	Surface Mount
Package / Case	24-UFQFN Exposed Pad
Supplier Device Package	24-QFN (4x4)
Purchase URL	https://www.e-xfl.com/product-detail/infineon-technologies/cy8c4014lqs-422

Contents

Block Diagram



Functional Description

PSoC 4000 devices include extensive support for programming, testing, debugging, and tracing both hardware and firmware.

The ARM Serial-Wire Debug (SWD) interface supports all programming and debug features of the device.

Complete debug-on-chip functionality enables full-device debugging in the final system using the standard production device. It does not require special interfaces, debugging pods, simulators, or emulators. Only the standard programming connections are required to fully support debug.

The PSoC Creator IDE provides fully integrated programming and debug support for the PSoC 4000 devices. The SWD interface is fully compatible with industry-standard third-party tools. The PSoC 4000 family provides a level of security not possible with multi-chip application solutions or with microcontrollers. It has the following advantages:

- Allows disabling of debug features
- Robust flash protection
- Allows customer-proprietary functionality to be implemented in on-chip programmable blocks

The debug circuits are enabled by default and can only be disabled in firmware. If they are not enabled, the only way to re-enable them is to erase the entire device, clear flash protection, and reprogram the device with new firmware that enables debugging.

Additionally, all device interfaces can be permanently disabled (device security) for applications concerned about phishing attacks due to a maliciously reprogrammed device or attempts to defeat security by starting and interrupting flash programming sequences. All programming, debug, and test interfaces are disabled when maximum device security is enabled. Therefore, PSoC 4000, with device security enabled, will have only limited capability for failure analysis. This is a trade-off the PSoC 4000 allows the customer to make.

Functional Overview

CPU and Memory Subsystem

CPU

The Cortex-M0 CPU in the PSoC 4000 is part of the 32-bit MCU subsystem, which is optimized for low-power operation with extensive clock gating. Most instructions are 16 bits in length and the CPU executes a subset of the Thumb-2 instruction set. This enables fully compatible, binary, upward migration of the code to higher performance processors, such as the Cortex-M3 and M4. It includes a nested vectored interrupt controller (NVIC) block with eight interrupt inputs and also includes a Wakeup Interrupt Controller (WIC). The WIC can wake the processor from the Deep Sleep mode, allowing power to be switched off to the main processor when the chip is in the Deep Sleep mode.

The CPU also includes a debug interface, the SWD interface, which is a 2-wire form of JTAG. The debug configuration used for PSoC 4000 has four breakpoint (address) comparators and two watchpoint (data) comparators.

Flash

The PSoC 4000 device has a flash module with a flash accelerator, tightly coupled to the CPU to improve average access times from the flash block. The low-power flash block is designed to deliver zero wait-state (WS) access time at 16 MHz. The flash accelerator delivers 85% of the single-cycle SRAM access performance on average.

SRAM

Two KB of SRAM are provided with zero wait-state access at 16 MHz.

SROM

A supervisory ROM that contains boot and configuration routines is provided.

System Resources

Power System

The power system is described in detail in the section on Power on page 8. It provides an assurance that voltage levels are as required for each respective mode and either delays mode entry (for example, on power-on reset (POR)) until voltage levels are as required for proper functionality, or generates resets (for example, on brown-out detection). The PSoC 4000 operates with a single external supply over the range of either 1.8 V ±5% (externally regulated) or 1.8 to 5.5 V (internally regulated) and has three different power modes, transitions between which are managed by the power system. The PSoC 4000 provides Active, Sleep, and Deep Sleep low-power modes.

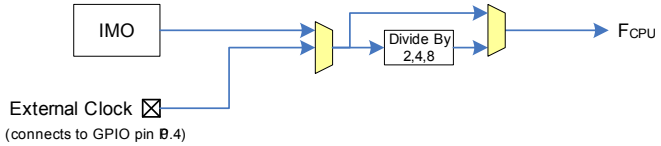
All subsystems are operational in Active mode. The CPU subsystem (CPU, flash, and SRAM) is clock-gated off in Sleep mode, while all peripherals and interrupts are active with instantaneous wake-up on a wake-up event. In Deep Sleep mode, the high-speed clock and associated circuitry is switched off; wake-up from this mode takes 35 µS.

Clock System

The PSoC 4000 clock system is responsible for providing clocks to all subsystems that require clocks and for switching between different clock sources without glitching. In addition, the clock system ensures that there are no metastable conditions.

The clock system for the PSoC 4000 consists of the internal main oscillator (IMO) and the internal low-frequency oscillator (ILO) and provision for an external clock.

Figure 1. PSoC 4000 MCU Clocking Architecture



The F_{CPU} signal can be divided down to generate synchronous clocks for the analog and digital peripherals. There are four clock dividers for the PSoC 4000, each with 16-bit divide capability The 16-bit capability allows flexible generation of fine-grained frequency values and is fully supported in PSoC Creator.

IMO Clock Source

The IMO is the primary source of internal clocking in the PSoC 4000. It is trimmed during testing to achieve the specified accuracy.The IMO default frequency is 24 MHz and it can be adjusted from 24 to 48 MHz in steps of 4 MHz. The IMO tolerance with Cypress-provided calibration settings is ±2% (24 and 32 MHz).

ILO Clock Source

The ILO is a very low power, 40-kHz oscillator, which is primarily used to generate clocks for the watchdog timer (WDT) and peripheral operation in Deep Sleep mode. ILO-driven counters can be calibrated to the IMO to improve accuracy. Cypress provides a software component, which does the calibration.

Watchdog Timer

A watchdog timer is implemented in the clock block running from the ILO; this allows watchdog operation during Deep Sleep and generates a watchdog reset if not serviced before the set timeout occurs. The watchdog reset is recorded in a Reset Cause register, which is firmware readable.

Reset

The PSoC 4000 can be reset from a variety of sources including a software reset. Reset events are asynchronous and guarantee reversion to a known state. The reset cause is recorded in a register, which is sticky through reset and allows software to determine the cause of the reset. An XRES pin is reserved for external reset on the 24-pin package. An internal POR is provided on the 16-pin package. The XRES pin has an internal pull-up resistor that is always enabled.

Voltage Reference

The PSoC 4000 reference system generates all internally required references. A 1.2-V voltage reference is provided for the comparator. The IDACs are based on a ±5% reference.

Descriptions of the Pin functions are as follows:

VDD: Power supply for both analog and digital sections.

VSS: Ground pin.

VCCD: Regulated digital supply (1.8 V ±5%).

Pins belonging to Ports 0, 1, and 2 can all be used as CSD sense and shield pins can be connected to AMUXBUS A or B or can all be used as GPIO pins that can be driven by the firmware.

Pins on Port 3 can be used as GPIO, in addition to their alternate functions listed above.

The following packages are provided: 24-pin QFN and 16-pin SOIC.

Figure 2. 24-pin QFN Pinout

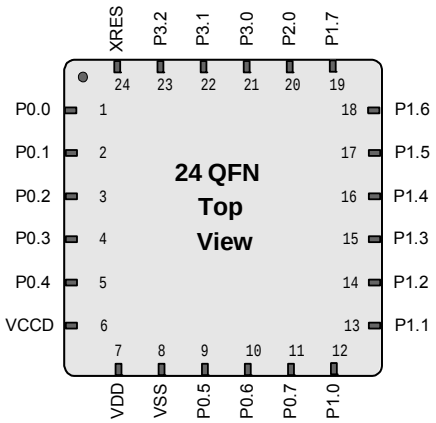
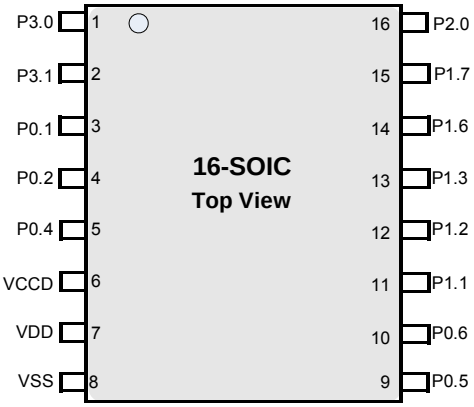


Figure 3. 16-pin SOIC Pinout



Development Support

The PSoC 4000 family has a rich set of documentation, development tools, and online resources to assist you during your development process. Visit www.cypress.com/go/psoc4 to find out more.

Documentation

A suite of documentation supports the PSoC 4000 family to ensure that you can find answers to your questions quickly. This section contains a list of some of the key documents.

Software User Guide: A step-by-step guide for using PSoC Creator. The software user guide shows you how the PSoC Creator build process works in detail, how to use source control with PSoC Creator, and much more.

Component Datasheets: The flexibility of PSoC allows the creation of new peripherals (components) long after the device has gone into production. Component data sheets provide all of the information needed to select and use a particular component, including a functional description, API documentation, example code, and AC/DC specifications.

Application Notes: PSoC application notes discuss a particular application of PSoC in depth; examples include brushless DC motor control and on-chip filtering. Application notes often include example projects in addition to the application note document.

Technical Reference Manual: The Technical Reference Manual (TRM) contains all the technical detail you need to use a PSoC device, including a complete description of all PSoC registers. The TRM is available in the Documentation section at www.cypress.com/psoc4.

Online

In addition to print documentation, the Cypress PSoC forums connect you with fellow PSoC users and experts in PSoC from around the world, 24 hours a day, 7 days a week.

Tools

With industry standard cores, programming, and debugging interfaces, the PSoC 4000 family is part of a development tool ecosystem. Visit us at www.cypress.com/go/psoccreator for the latest information on the revolutionary, easy to use PSoC Creator IDE, supported third party compilers, programmers, debuggers, and development kits.

Electrical Specifications

Absolute Maximum Ratings

Table 2. Absolute Maximum Ratings[1]

Spec ID#	Parameter	Description	Min	Typ	Max	Units	Details/ Conditions
SID1	V_{DDD_ABS}	Digital supply relative to V_{SS}	–0.5	–	6	V	
SID2	V_{CCD_ABS}	Direct digital core voltage input relative to V_{SS}	–0.5	–	1.95	V	
SID3	V_{GPIO_ABS}	GPIO voltage	–0.5	–	V_{DD}+0.5	V	
SID4	I_{GPIO_ABS}	Maximum current per GPIO	–25	–	25	mA	
SID5	$I_{GPIO\_injection}$	GPIO injection current, Max for V_{IH} > V_{DDD}, and Min for V_{IL} < V_{SS}	–0.5	–	0.5	mA	Current injected per pin
BID44	ESD_HBM	Electrostatic discharge human body model	2200	–	–	V	
BID45	ESD_CDM	Electrostatic discharge charged device model	500	–	–	V	
BID46	LU	Pin current for latch-up	–140	–	140	mA	

Note
1. Usage above the absolute maximum conditions listed in Table 1 may cause permanent damage to the device. Exposure to Absolute Maximum conditions for extended periods of time may affect device reliability. The Maximum Storage Temperature is 150 °C in compliance with JEDEC Standard JESD22-A103, High Temperature Storage Life. When used below Absolute Maximum conditions but above normal operating conditions, the device may not operate to specification.

Device Level Specifications

All specifications are valid for –40 °C ≤ T_A ≤ 85 °C for A grade devices and –40 °C ≤ T_A ≤ 105 °C for S grade devices, except where noted. Specifications are valid for 1.71 V to 5.5 V, except where noted.

Table 3. DC Specifications

Typical values measured at V_{DD} = 3.3 V and 25 °C.

Spec ID#	Parameter	Description	Min	Typ	Max [2]	Units	Details/ Conditions
SID53	V_{DD}	Power supply input voltage	1.8	–	5.5	V	With regulator enabled
SID255	V_{DD}	Power supply input voltage (V_{CCD} = V_{DD})	1.71	–	1.89	V	Internally unregulated supply
SID54	V_{DDIO}	V_{DDIO} domain supply	1.71	–	V_{DD}	V	
SID55	C_{EFC}	External regulator voltage bypass	–	0.1	–	µF	X5R ceramic or better
SID56	C_{EXC}	Power supply bypass capacitor	–	1	–	µF	X5R ceramic or better
Active Mode, V_{DD} = 1.8 to 5.5 V							
SID9	I_{DD5}	Execute from flash; CPU at 6 MHz	–	2.0	2.85	mA	
SID12	I_{DD8}	Execute from flash; CPU at 12 MHz	–	3.2	3.75	mA	
SID16	I_{DD11}	Execute from flash; CPU at 16 MHz	–	4.0	4.5	mA	
Sleep Mode, V_{DDD} = 1.71 to 5.5 V							
SID25	I_{DD20}	I^2C wakeup, WDT on. 6 MHz	–	1.1	–	mA	
SID25A	I_{DD20A}	I^2C wakeup, WDT on. 12 MHz	–	1.4	–	mA	
Deep Sleep Mode, V_{DD} = 1.8 to 3.6 V (Regulator on)							
SID31	I_{DD26}	I^2C wakeup and WDT on	–	2.5	8.2	µA	
Deep Sleep Mode, V_{DD} = 3.6 to 5.5 V (Regulator on)							
SID34	I_{DD29}	I^2C wakeup and WDT on	–	2.5	12	µA	
Deep Sleep Mode, V_{DD} = V_{CCD} = 1.71 to 1.89 V (Regulator bypassed)							
SID37	I_{DD32}	I^2C wakeup and WDT on	–	2.5	9.2	µA	
XRES Current							
SID307	I_{DD_XR}	Supply current while XRES asserted	–	2	5	mA	

Note
2. Maximum values corresponds to values at higher temperature (105 °C).

Table 4. AC Specifications

Spec ID#	Parameter	Description	Min	Typ	Max	Units	Details/ Conditions
SID48	F_{CPU}	CPU frequency	DC	–	16	MHz	$1.71 \le V_{DD} \le 5.5$
SID49[3]	T_{SLEEP}	Wakeup from Sleep mode	–	0	–	µs	
SID50[3]	$T_{DEEPSLEEP}$	Wakeup from Deep Sleep mode	–	35	–	µs	

GPIO

Table 5. GPIO DC Specifications

Spec ID#	Parameter	Description	Min	Typ	Max	Units	Details/ Conditions
SID57	V_{IH}[4]	Input voltage high threshold	0.7 × V_{DDD}	–	–	V	CMOS Input
SID58	V_{IL}	Input voltage low threshold	–	–	0.3 × V_{DDD}	V	CMOS Input
SID241	V_{IH}[4]	LVTTL input, V_{DDD} < 2.7 V	0.7× V_{DDD}	–	–	V	
SID242	V_{IL}	LVTTL input, V_{DDD} < 2.7 V	–	–	0.3 × V_{DDD}	V	
SID243	V_{IH}[4]	LVTTL input, $V_{DDD} \ge 2.7$ V	2.0	–	–	V	
SID244	V_{IL}	LVTTL input, $V_{DDD} \ge 2.7$ V	–	–	0.8	V	
SID59	V_{OH}	Output voltage high level	V_{DDD} –0.6	–	–	V	I_{OH} = 4 mA at 3 V V_{DDD}
SID60	V_{OH}	Output voltage high level	V_{DDD} –0.5	–	–	V	I_{OH} = 1 mA at 1.8 V V_{DDD}
SID61	V_{OL}	Output voltage low level	–	–	0.6	V	I_{OL} = 4 mA at 1.8 V V_{DDD}
SID62	V_{OL}	Output voltage low level	–	–	0.6	V	I_{OL} = 10 mA at 3 V V_{DDD}
SID62A	V_{OL}	Output voltage low level	–	–	0.4	V	I_{OL} = 3 mA at 3 V V_{DDD}
SID63	R_{PULLUP}	Pull-up resistor	3.5	5.6	8.5	kΩ	
SID64	$R_{PULLDOWN}$	Pull-down resistor	3.5	5.6	8.5	kΩ	
SID65	I_{IL}	Input leakage current (absolute value)	–	–	2	nA	25 °C, V_{DDD} = 3.0 V
SID66	C_{IN}	Input capacitance	–	3	7	pF	
SID67[5]	V_{HYSTTL}	Input hysteresis LVTTL	15	40	–	mV	$V_{DDD} \ge 2.7$ V
SID68[5]	$V_{HYSCMOS}$	Input hysteresis CMOS	0.05 × V_{DDD}	–	–	mV	V_{DD} < 4.5 V
SID68A[5]	$V_{HYSCMOS5V5}$	Input hysteresis CMOS	200	–	–	mV	V_{DD} > 4.5 V
SID69[5]	I_{DIODE}	Current through protection diode to V_{DD}/V_{SS}	–	–	100	µA	
SID69A[5]	I_{TOT_GPIO}	Maximum total source or sink chip current	–	–	85	mA	

Notes
3. Guaranteed by characterization.
4. V_{IH} must not exceed V_{DDD} + 0.2 V.
5. Guaranteed by characterization.

Table 6. GPIO AC Specifications

(Guaranteed by Characterization)

Spec ID#	Parameter	Description	Min	Typ	Max	Units	Details/ Conditions
SID70	T_{RISEF}	Rise time in fast strong mode	2	–	12	ns	3.3 V V_{DDD}, Cload = 25 pF
SID71	T_{FALLF}	Fall time in fast strong mode	2	–	12	ns	3.3 V V_{DDD}, Cload = 25 pF
SID72	T_{RISES}	Rise time in slow strong mode	10	–	60	–	3.3 V V_{DDD}, Cload = 25 pF
SID73	T_{FALLS}	Fall time in slow strong mode	10	–	60	–	3.3 V V_{DDD}, Cload = 25 pF
SID74	$F_{GPIOUT1}$	GPIO F_{OUT}; 3.3 V ≤ V_{DDD} ≤ 5.5 V. Fast strong mode.	–	–	16	MHz	90/10%, 25 pF load, 60/40 duty cycle
SID75	$F_{GPIOUT2}$	GPIO F_{OUT}; 1.71 V≤ V_{DDD}≤ 3.3 V. Fast strong mode.	–	–	16	MHz	90/10%, 25 pF load, 60/40 duty cycle
SID76	$F_{GPIOUT3}$	GPIO F_{OUT}; 3.3 V ≤ V_{DDD} ≤ 5.5 V. Slow strong mode.	–	–	7	MHz	90/10%, 25 pF load, 60/40 duty cycle
SID245	$F_{GPIOUT4}$	GPIO F_{OUT}; 1.71 V ≤ V_{DDD} ≤ 3.3 V. Slow strong mode.	–	–	3.5	MHz	90/10%, 25 pF load, 60/40 duty cycle
SID246	F_{GPIOIN}	GPIO input operating frequency; 1.71 V ≤ V_{DDD} ≤ 5.5 V	–	–	16	MHz	90/10% V_{IO}

XRES

Table 7. XRES DC Specifications

Spec ID#	Parameter	Description	Min	Typ	Max	Units	Details/ Conditions
SID77	V_{IH}	Input voltage high threshold	0.7 × V_{DDD}	–	–	V	CMOS Input
SID78	V_{IL}	Input voltage low threshold	–	–	0.3 × V_{DDD}	V	CMOS Input
SID79	R_{PULLUP}	Pull-up resistor	3.5	5.6	8.5	kΩ	
SID80	C_{IN}	Input capacitance	–	3	7	pF	
SID81[6]	$V_{HYSXRES}$	Input voltage hysteresis	–	05*V_{DD}	–	mV	Typical hysteresis is 200 mV for V_{DD} > 4.5V

Table 8. XRES AC Specifications

Spec ID#	Parameter	Description	Min	Typ	Max	Units	Details/ Conditions
SID83[6]	$T_{RESETWIDTH}$	Reset pulse width	5	–	–	µs	
BID#194[6]	$T_{RESETWAKE}$	Wake-up time from reset release	–	–	3	ms	

Note
6. Guaranteed by characterization.

Analog Peripherals

Comparator

Table 9. Comparator DC Specifications

Spec ID#	Parameter	Description	Min	Typ	Max	Units	Details/ Conditions
SID330[6]	I_{CMP1}	Block current, High Bandwidth mode	–	–	110	µA	
SID331[6]	I_{CMP2}	Block current, Low Power mode	–	–	85	µA	
SID332[6]	$V_{OFFSET1}$	Offset voltage, High Bandwidth mode	–	10	30	mV	
SID333[6]	$V_{OFFSET2}$	Offset voltage, Low Power mode	–	10	30	V	
SID334[6]	Z_{CMP}	DC input impedance of comparator	35	–	–	MΩ	
SID338[6]	VINP_COMP	Comparator input range	0	–	3.6	V	Max input voltage is lower of 3.6 V or V_{DD}

Table 10. Comparator AC Specifications (Guaranteed by Characterization)

Spec ID#	Parameter	Description	Min	Typ	Max	Units	Details/ Conditions
SID336[6]	T_{COMP1}	Response Time High Bandwidth mode, 50-mV overdrive	–	–	90	ns	
SID337[6]	T_{COMP2}	Response Time Low Power mode, 50-mV overdrive	–	–	110	ns	

I²C

Table 13. Fixed I²C DC Specifications[8]

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/Conditions
SID149	I_{I2C1}	Block current consumption at 100 kHz	–	–	25	µA	
SID150	I_{I2C2}	Block current consumption at 400 kHz	–	–	135	µA	
SID152	I_{I2C4}	I²C enabled in Deep Sleep mode	–	–	2.5	µA	

Table 14. Fixed I²C AC Specifications[8]

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/Conditions
SID153	F_{I2C1}	Bit rate	–	–	400	Kbps	

Note
8. Guaranteed by characterization.

Memory

Table 15. Flash DC Specifications

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/Conditions
SID173	V_{PE}	Erase and program voltage	1.71	–	5.5	V	

Table 16. Flash AC Specifications

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/Conditions
SID174	$T_{ROWWRITE}$[9]	Row (block) write time (erase and program)	–	–	20	ms	Row (block) = 128 bytes
SID175	$T_{ROWERASE}$[9]	Row erase time	–	–	13	ms	
SID176	$T_{ROWPROGRAM}$[9]	Row program time after erase	–	–	7	ms	
SID178	$T_{BULKERASE}$[9]	Bulk erase time (16 KB)	–	–	15	ms	
SID180[10]	$T_{DEVPROG}$[9]	Total device program time	–	–	7.5	seconds	
SID181[10]	F_{END}	Flash endurance	100 K	–	–	cycles	
SID182[10]	F_{RET}	Flash retention. $T_A \leq 55$ °C, 100 K P/E cycles	20 [11]	–	–	years	
SID182A[10]		Flash retention. $T_A \leq 85$ °C, 10 K P/E cycles	10 [12]	–	–	years	

System Resources

Power-on Reset (POR)

Table 17. Power On Reset (PRES)

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/Conditions
SID.CLK#6	SR_POWER_UP	Power supply slew rate	1	–	67	V/ms	At power-up
SID185[10]	$V_{RISEIPOR}$	Rising trip voltage	0.80	–	1.5	V	
SID186[10]	$V_{FALLIPOR}$	Falling trip voltage	0.70	–	1.4	V	

Table 18. Brown-out Detect (BOD) for V_{CCD}

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/Conditions
SID190[10]	$V_{FALLPPOR}$	BOD trip voltage in active and sleep modes	1.48	–	1.62	V	
SID192[10]	$V_{FALLDPSLP}$	BOD trip voltage in Deep Sleep	1.11	–	1.5	V	

Notes

9. It can take as much as 20 milliseconds to write to Flash. During this time the device should not be Reset, or Flash operations will be interrupted and cannot be relied on to have completed. Reset sources include the XRES pin, software resets, CPU lockup states and privilege violations, improper power supply levels, and watchdogs. Make certain that these are not inadvertently activated.
10. Guaranteed by characterization.
11. Cypress provides a retention calculator to calculate the retention lifetime based on customers' individual temperature profiles for operation over the –40 °C to +105 °C ambient temperature range. Contact customercare@cypress.com.
12. Cypress provides a retention calculator to calculate the retention lifetime based on customers' individual temperature profiles for operation over the –40 °C to +105 °C ambient temperature range. Contact customercare@cypress.com.

Table 24. External Clock Specifications

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/Conditions
SID305[14]	ExtClkFreq	External clock input frequency	0	–	16	MHz	
SID306[14]	ExtClkDuty	Duty cycle; measured at $V_{DD/2}$	45	–	55	%	

Table 25. Block Specs

Spec ID	Parameter	Description	Min	Typ	Max	Units	Details/Conditions
SID262[14]	$T_{CLKSWITCH}$	System clock source switching time	3	–	4	Periods	

Note
14. Guaranteed by characterization.

Ordering Information

The PSoC 4000 part numbers and features are listed in the following table.

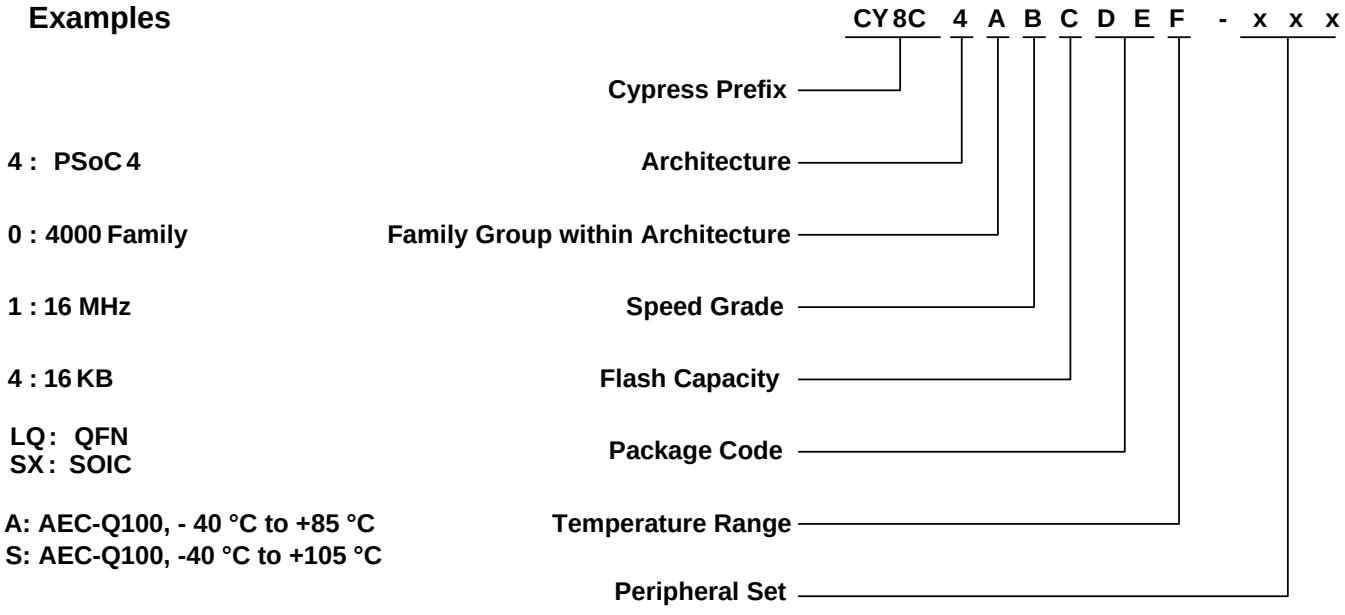
MPN	Features									Package		Operating Temperature	
	Max CPU Speed (MHz)	Flash (KB)	SRAM (KB)	CapSense	7-bit IDAC	8-bit IDAC	Comparators	TCPWM Blocks	SCB (I2C)	16-SOIC	24-QFN	–40 to +85 °C	–40 to +105 °C
CY8C4014SXA-421	16	16	2	✔	1	1	1	1	1	✔	–	✔	–
CY8C4014LQA-422	16	16	2	✔	1	1	1	1	1	–	✔	✔	–
CY8C4014SXS-421	16	16	2	✔	1	1	1	1	1	✔	–	–	✔
CY8C4014LQS-422	16	16	2	✔	1	1	1	1	1	–	✔	–	✔

Part Numbering Conventions

PSoC 4 devices follow the part numbering convention described in the following table. All fields are single-character alphanumeric (0, 1, 2, …, 9, A,B, …, Z) unless stated otherwise.

The part numbers are of the form CY8C4ABCDEF-XYZ where the fields are defined as follows.

Examples



Packaging

Table 26. Package List

Spec ID#	Package	Description
BID#26	24-pin QFN	24-pin 4 x 4 x 0.6 mm QFN with 0.5-mm pitch
BID#40	16-pin SOIC	16-pin (150 Mil) SOIC

Table 27. Package Characteristics

Parameter	Description	Conditions	Min	Typ	Max	Units
T_A	Operating ambient temperature	For A grade devices	–40	25.00	85	°C
T_A	Operating ambient temperature	For S grade devices	–40	25.00	105	°C
T_J	Operating junction temperature	For A grade devices	–40	–	100	°C
T_J	Operating junction temperature	For S grade devices	–40	–	120	°C
T_{JA}	Package θ_{JA} (24-pin QFN)		–	38.01	–	°C/W
T_{JA}	Package θ_{JA} (16-pin SOIC)		–	142.14	–	°C/W

Table 28. Solder Reflow Peak Temperature

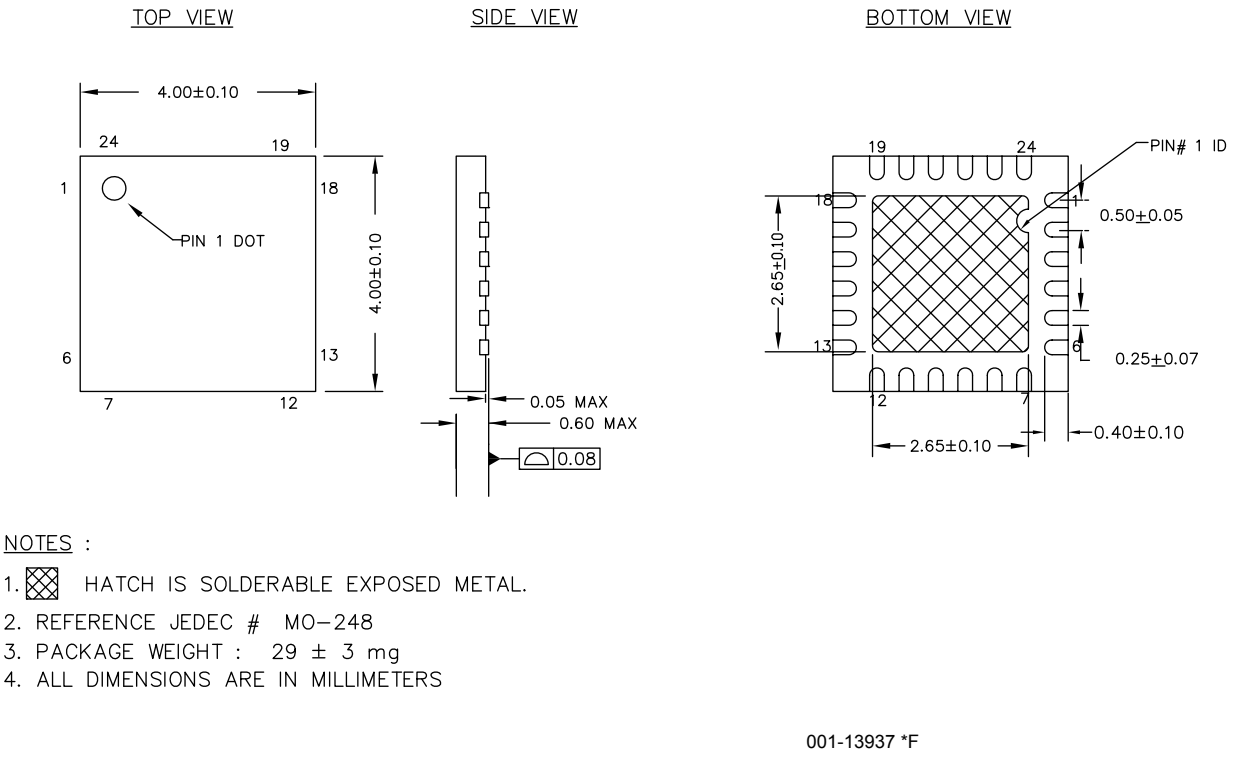
Package	Maximum Peak Temperature	Maximum Time at Peak Temperature
All	260 °C	30 seconds

Table 29. Package Moisture Sensitivity Level (MSL), IPC/JEDEC J-STD-020

Package	MSL
All	MSL 3

Package Outline Drawings

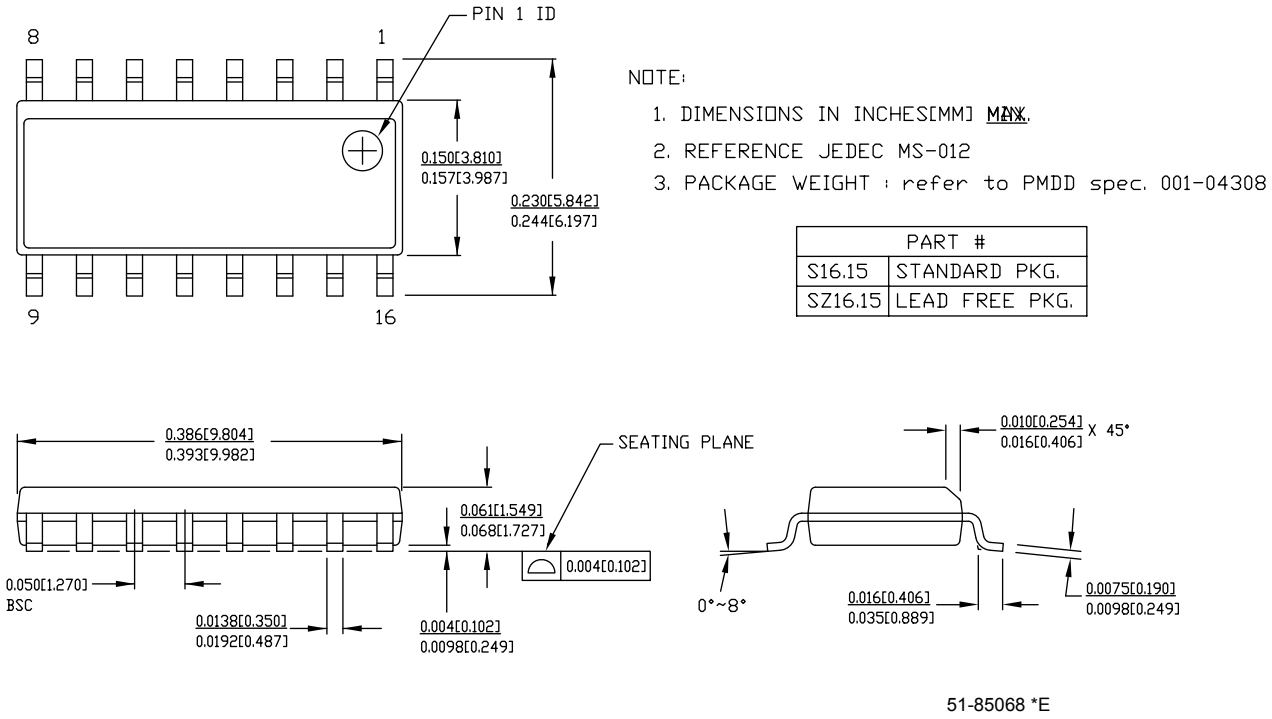
Figure 6. 24-pin QFN (4 × 4 × 0.55 mm) LQ24A 2.65 × 2.65 E-Pad (Sawn) Package Outline, 001-13937



The center pad on the QFN package should be connected to ground (VSS) for best mechanical, thermal, and electrical performance. If not connected to ground, it should be electrically floating and not connected to any other signal.

Note
15. Dimensions of the QFN package drawings are in millimeters.

Figure 7. 16-pin SOIC (150 Mils) S16.15/SZ16.15 Package Outline, 51-85068



Acronyms

Table 30. Acronyms Used in this Document

Acronym	Description
abus	analog local bus
ADC	analog-to-digital converter
AG	analog global
AHB	AMBA (advanced microcontroller bus architecture) high-performance bus, an ARM data transfer bus
ALU	arithmetic logic unit
AMUXBUS	analog multiplexer bus
API	application programming interface
APSR	application program status register
ARM®	advanced RISC machine, a CPU architecture
ATM	automatic thump mode
BW	bandwidth
CAN	Controller Area Network, a communications protocol
CMRR	common-mode rejection ratio
CPU	central processing unit
CRC	cyclic redundancy check, an error-checking protocol
DAC	digital-to-analog converter, see also IDAC, VDAC
DFB	digital filter block
DIO	digital input/output, GPIO with only digital capabilities, no analog. See GPIO.
DMIPS	Dhrystone million instructions per second
DMA	direct memory access, see also TD
DNL	differential nonlinearity, see also INL
DNU	do not use
DR	port write data registers
DSI	digital system interconnect
DWT	data watchpoint and trace
ECC	error correcting code
ECO	external crystal oscillator
EEPROM	electrically erasable programmable read-only memory
EMI	electromagnetic interference
EMIF	external memory interface
EOC	end of conversion
EOF	end of frame
EPSR	execution program status register
ESD	electrostatic discharge

Table 30. Acronyms Used in this Document *(continued)*

Acronym	Description
ETM	embedded trace macrocell
FIR	finite impulse response, see also IIR
FPB	flash patch and breakpoint
FS	full-speed
GPIO	general-purpose input/output, applies to a PSoC pin
HVI	high-voltage interrupt, see also LVI, LVD
IC	integrated circuit
IDAC	current DAC, see also DAC, VDAC
IDE	integrated development environment
I^2C, or IIC	Inter-Integrated Circuit, a communications protocol
IIR	infinite impulse response, see also FIR
ILO	internal low-speed oscillator, see also IMO
IMO	internal main oscillator, see also ILO
INL	integral nonlinearity, see also DNL
I/O	input/output, see also GPIO, DIO, SIO, USBIO
IPOR	initial power-on reset
IPSR	interrupt program status register
IRQ	interrupt request
ITM	instrumentation trace macrocell
LCD	liquid crystal display
LIN	Local Interconnect Network, a communications protocol.
LR	link register
LUT	lookup table
LVD	low-voltage detect, see also LVI
LVI	low-voltage interrupt, see also HVI
LVTTL	low-voltage transistor-transistor logic
MAC	multiply-accumulate
MCU	microcontroller unit
MISO	master-in slave-out
NC	no connect
NMI	nonmaskable interrupt
NRZ	non-return-to-zero
NVIC	nested vectored interrupt controller
NVL	nonvolatile latch, see also WOL
opamp	operational amplifier
PAL	programmable array logic, see also PLD
PC	program counter
PCB	printed circuit board

Document History Page *(continued)*

Description Title: Automotive PSoC® 4: PSoC 4000 Family Datasheet Programmable System-on-Chip (PSoC®) Document Number: 001-92145				
Revision	**ECN**	**Orig. of Change**	**Submission Date**	**Description of Change**
*B (cont.)	4594824	JICG	12/12/2014	Updated Packaging: Updated Table 27: Added values for T_J parameter corresponding to Condition “For A grade devices”. Changed maximum value of T_J parameter corresponding to Condition “For S grade devices” from 100 °C to 120 °C. Removed T_{JC} parameter and its details.
*C	4615131	SNPR	01/06/2015	Changed status from Preliminary to Final.
*D	4669514	KUK	02/24/2015	Updated Ordering Information: No change in part numbers. Updated Part Numbering Conventions.
*E	5141209	KIKU	02/17/2016	Updated Block Diagram: Added Low Power Comparator block. Updated Pinouts: Updated Table 1: Updated details in “Name” column of pin 14 and pin 15 corresponding to 24-pin QFN and also updated details in “Alternate Functions” column corresponding to same pins. Updated details in “Name” column of pin 12 and pin 13 corresponding to 16-pin SOIC and also updated details in “Alternate Functions” column corresponding to same pins. Updated Packaging: Updated Package Outline Drawings: spec 001-13937 – Changed revision from *E to *F. Updated to new template.

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